# **Guide for Conformal Coated Tantalum Capacitors**

## INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

## THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS			
DIELECTRIC	e DIELECTRIC CONSTANT		
Air or vacuum	1.0		
Paper	2.0 to 6.0		
Plastic	2.1 to 6.0		
Mineral oil	2.2 to 2.3		
Silicone oil	2.7 to 2.8		
Quartz	3.8 to 4.4		
Glass	4.8 to 8.0		
Porcelain	5.1 to 5.9		
Mica	5.4 to 8.7		
Aluminum oxide	8.4		
Tantalum pentoxide	26		
Ceramic	12 to 400K		

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



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#### SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

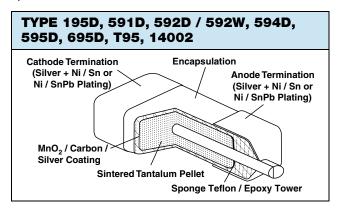
The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the can in which it will be enclosed. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost.

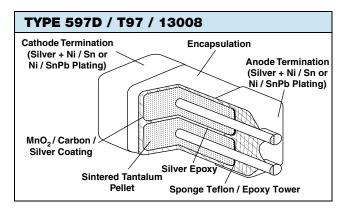
Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

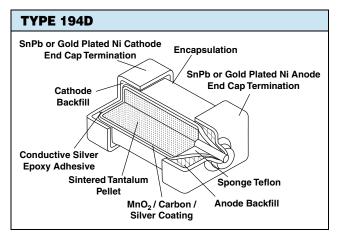
# TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

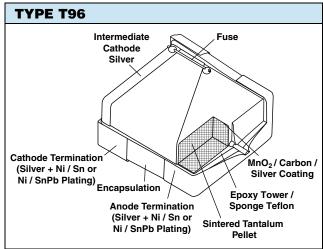
Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

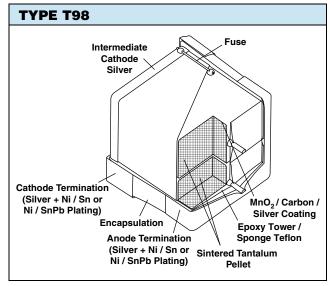
Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.











#### Note

 For all types of conformal coated capacitors, tantalum wire to tantalum pellet attachment method could be either embedded (see images on the left side of the page) or welded (see images on the right side), depending on specific rating



## **COMMERCIAL PRODUCTS**

SOLID TANTALUM CAPACITORS - CONFORMAL COATED					
SERIES	592W	592D	591D	595D	594D
PRODUCT IMAGE					
TYPE		Surface mount	TANTAMOUNT™ chip, co	nformal coated	
FEATURES	Low profile, robust design for use in pulsed applications	Low profile, maximum CV	Low profile, low ESR, maximum CV	Maximum CV	Low ESR, maximum CV
TEMPERATURE RANGE	-55 °C to +125 °C (above 40 °C, voltage deratig is required)	-55 °C to +125 °C (above 85 °C, voltage derating is required)			
CAPACITANCE RANGE	330 μF to 2200 μF	1 μF to 2200 μF	1 μF to 1500 μF	0.1 μF to 1500 μF	1 μF to 1500 μF
VOLTAGE RANGE	6 V to 10 V	4 V to 50 V	4 V to 50 V	4 V to 50 V	4 V to 50 V
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %
LEAKAGE CURRENT		0.01 CV or 0.5 μA, whichever is greater			
DISSIPATION FACTOR	14 % to 45 %	4 % to 50 %	4 % to 50 %	4 % to 20 %	4 % to 20 %
CASE CODES	C, M, X	S, A, B, C, D, R, M, X	A, B, C, D, R, M	T, S, A, B, C, D, G, M, R	B, C, D, R
TERMINATION	100 % matte tin	100 %	matte tin standard, tin /	lead and gold plated av	vailable

SOLID TANTAL	UM CAPACITORS - C	UM CAPACITORS - CONFORMAL COATED					
SERIES	597D	695D	195D	194D			
PRODUCT IMAGE							
TYPE		Tantamount™ chip	o, conformal coated				
FEATURES	Ultra low ESR, maximum CV, multi-anode	Pad compatible with 194D and CWR06	US and European case sizes	Industrial version of CWR06 / CWR16			
TEMPERATURE RANGE	-55 °C to +125 °C (above 85 °C, voltage derating is required)						
CAPACITANCE RANGE	10 μF to 2200 μF	0.1 μF to 270 μF	0.1 μF to 330 μF	0.1 μF to 330 μF			
VOLTAGE RANGE	4 V to 75 V	4 V to 50 V	2 V to 50 V	4 V to 50 V			
CAPACITANCE TOLERANCE	± 10 %, ± 20 %						
LEAKAGE CURRENT		0.01 CV or 0.5 μA, ν	whichever is greater				
DISSIPATION FACTOR	6 % to 20 %	4 % to 8 %	4 % to 8 %	4 % to 10 %			
CASE CODES	V, D, E, R, F, Z, M, H	A, B, D, E, F, G, H	C, S, V, X, Y, Z, R, A, B, D, E, F, G, H	A, B, C, D, E, F, G, H			
TERMINATION	100 % matte tin standard, tin / lead solder plated available	Gold plated star 100 % matte tin standard, tin / lead solder tin / lead and gold plated available and hot sold dipped availa					

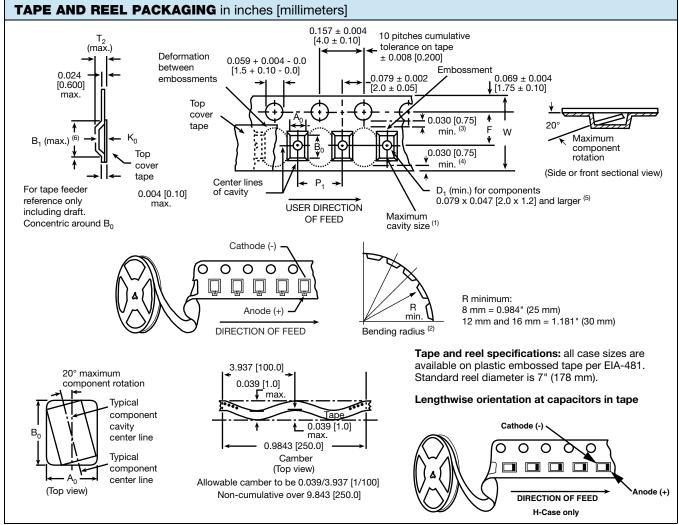


## **HIGH RELIABILITY PRODUCTS**

SOLID TANTALUM CA	SOLID TANTALUM CAPACITORS - CONFORMAL COATED					
SERIES	CWR06	CWR16	CWR26	13008	14002	
PRODUCT IMAGE						
TYPE		TANTAMO	DUNT™ chip, conforma	al coated		
FEATURES	MIL-PRF-55365/4 qualified	I I A approved				
TEMPERATURE RANGE	-55 °C to +125 °C (above 85 °C, voltage derating is required)					
CAPACITANCE RANGE	0.10 μF to 100 μF	0.33 μF to 330 μF	10 μF to 100 μF	10 μF to 1500 μF	4.7 μF to 680 μF	
VOLTAGE RANGE	4 V to 50 V	V to 50 V 4 V to 35 V 15 V to 35 V 4 V to 63 V				
CAPACITANCE TOLERANCE	± 5 %, ± 10 %, ± 20 %  ± 5 %, ± 10 %, ± 20 %  ± 5 %, ± 10 %, ± 20 %  ± 10 %, ± 20 %  ± 10 %,				± 10 %, ± 20 %	
LEAKAGE CURRENT	0.01 CV or 1.0 μA, whichever is greater 0.01 CV or 0.5 μA, whichever is greater					
DISSIPATION FACTOR	6 % to 10 %	6 % to 10 %	6 % to 12 %	6 % to 20 %	6 % to 14 %	
CASE CODES	A, B, C, D, E, F, G, H	A, B, C, D, E, F, G, H	F, G, H	V, E, F, R, Z, D, M, H, N	B, C, D, R	
TERMINATION	Gold plated	l; tin / lead; tin / lead s	solder fused	Tin /	lead	

SOLID TANTALUM CA	SOLID TANTALUM CAPACITORS - CONFORMAL COATED					
SERIES	T95	Т96	T97	T98		
PRODUCT IMAGE						
TYPE		TANTAMOUNT™ chip, Hi-Re	el COTS, conformal coated			
FEATURES	High reliability	High reliability, built in fuse	High reliability, ultra low ESR, multi-anode	High reliability, ultra low ESR, built in fuse, multi-anode		
TEMPERATURE RANGE	-55	°C to +125 °C (above 85 °	C, voltage derating is requir	red)		
CAPACITANCE RANGE	0.15 μF to 680 μF	10 μF to 680 μF	10 μF to 2200 μF	10 μF to 1500 μF		
VOLTAGE RANGE	4 V to 50 V	4 V to 50 V	4 V to 75 V	4 V to 75 V		
CAPACITANCE TOLERANCE	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %		
LEAKAGE CURRENT	0.01 CV or 0.5 μA, whichever is greater					
DISSIPATION FACTOR	4 % to 14 %	6 % to 14 %	6 % to 20 %	6 % to 10 %		
CASE CODES	A, B, C, D, R, S, V, X, Y, Z	R	V, E, F, R, Z, D, M, H, N	V, E, F, R, Z, M, H		
TERMINATION		100 % matte	tin, tin / lead			

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#### Notes

- · Metric dimensions will govern. Dimensions in inches are rounded and for reference only
- (1) A<sub>0</sub>, B<sub>0</sub>, K<sub>0</sub>, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A<sub>0</sub>, B<sub>0</sub>, K<sub>0</sub>) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less
- (5) The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other
- (6) B<sub>1</sub> dimension is a reference dimension tape feeder clearance only





CARRIER TAPE DIMENSIONS in inches [millimeters]						
TAPE WIDTH	W	D <sub>0</sub>	P <sub>2</sub>	F	E <sub>1</sub>	E <sub>2 min.</sub>
8 mm	0.315 + 0.012 / - 0.004 [8.0 + 0.3 / - 0.1]	0.078 ± 0.0019 [2.0 ± 0.05] 0.059 + 0.004 / - 0	0.14 ± 0.0019 [3.5 ± 0.05]		0.246 [6.25]	
12 mm	0.479 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.1]		0.059	0.216 ± 0.0019 [5.5 ± 0.05]	0.324 ± 0.004	0.403 [10.25]
16 mm	0.635 + 0.012 / - 0.004 [16.0 + 0.3 / - 0.1]	[1.5 + 0.1 / - 0]	0.078 ± 0.004	0.295 ± 0.004 [7.5 ± 0.1]	[1.75 ± 0.1]	0.570 [14.25]
24 mm	0.945 ± 0.012 [24.0 ± 0.3]		$[2.0 \pm 0.1]$	0.453 ± 0.004 [11.5 ± 0.1]		0.876 [22.25]

CARRIER T	APE DIMENSIONS in	inches [millimeters	[5]		
ТҮРЕ	CASE CODE	TAPE WIDTH W IN mm	P <sub>1</sub>	K <sub>0 max.</sub>	B <sub>1 max</sub> .
	A	8	0.157 ± 0.004	0.058 [1.47]	0.149 [3.78]
	В	12	[4.0 ± 0.10]	0.088 [2.23]	0.166 [4.21]
	С	12		0.088 [2.23]	0.290 [7.36]
	D	12	0.315 ± 0.004	0.088 [2.23]	0.300 [7.62]
592D 592W	М	16	[8.0 ± 0.10]	0.091 [2.30]	0.311 [7.90]
591D	R	12		0.088 [2.23]	0.296 [7.52]
	S	8	0.157 ± 0.004	0.058 [1.47]	0.139 [3.53]
	Т	12	[4.0 ± 0.10]	0.088 [2.23]	0.166 [4.21]
	Х	24	0.472 ± 0.004 [12.0 ± 0.10]	0.011 [2.72]	0.594 [15.1]
	A	8	0.157 ± 0.004	0.063 [1.60]	0.152 [3.86]
	В	12	$[4.0 \pm 0.10]$	0.088 [2.23]	0.166 [4.21]
	С	12		0.118 [2.97]	0.290 [7.36]
	D	12	0.315 ± 0.004	0.119 [3.02]	0.296 [7.52]
	G	12	$[8.0 \pm 0.10]$	0.111 [2.83]	0.234 [5.95]
595D	Н	12		0.098 [2.50]	0.232 [5.90]
594D	М	12	0.157 ± 0.004 [4.0 ± 0.10]	0.085 [2.15]	0.152 [3.85]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.148 [3.78]	0.296 [7.52]
	S	8	0.157 ± 0.004	0.058 [1.47]	0.149 [3.78]
	Т	8	$[4.0 \pm 0.10]$	0.054 [1.37]	0.093 [2.36]
	A	8		0.058 [1.47]	0.139 [3.53]
	В	12	0.157 ± 0.004	0.059 [1.50]	0.189 [4.80]
	D	12	[4.0 ± 0.10]	0.063 [1.62]	0.191 [4.85]
	Е	12	1	0.074 [1.88]	0.239 [6.07]
695D	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.075 [1.93]	0.259 [6.58]
	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
	Н	16	0.315 ± 0.004 [8.0 ± 0.10]	0.124 [3.15]	0.31 [7.87]



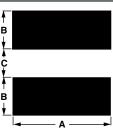
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		TAPE WIDTH			
TYPE	CASE CODE	W IN mm	P <sub>1</sub>	$K_{0 max.}$	B <sub>1 max.</sub>
	A	8		0.058 [1.47]	0.139 [3.53]
	В	12	1	0.058 [1.47]	0.189 [4.80]
	С	8	0.157 ± 0.004	0.059 [1.37]	
			$[4.0 \pm 0.10]$		0.093 [2.36]
	D	12		0.067 [1.70]	0.179 [4.55]
	E	12	0.045 0.004	0.074 [1.88]	0.239 [6.07]
	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.076 [1.93]	0.259 [6.58]
195D	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
.002	H <sup>(1)</sup>	12	0.472 ± 0.004 [12.0 ± 0.1]	0.122 [3.11]	0.163 [4.14]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.149 [3.78]	0.296 [7.52]
	S	8		0.058 [1.47]	0.149 [3.78]
	V	8	1	0.060 [1.52]	0.150 [3.80]
	X	12	$0.157 \pm 0.004$	0.069 [1.75]	0.296 [7.52]
	Y	12	[4.0 ± 0.10]	0.089 [2.26]	0.296 [7.52]
	Z	12	1	0.114 [2.89]	0.288 [7.31]
	A	8		0.069 [1.75]	0.139 [3.53]
	В	12	1	0.073 [1.85]	0.189 [4.80]
	C	12	$0.157 \pm 0.004$	0.069 [1.75]	0.244 [6.20]
194D CWR06 CWR16 CWR26	D	12	[4.0 ± 0.10]	0.068 [1.72]	0.191 [4.85]
	E	12		0.074 [1.88]	0.239 [6.07]
	F	12		0.091 [2.31]	0.262 [6.65]
	G	16	0.315 ± 0.004	0.134 [3.40]	0.289 [7.34]
	H	16	$[8.0 \pm 0.10]$	0.134 [3.40]	
	D D	16	0.047 0.004		0.319 [8.10]
			$0.317 \pm 0.004$ $[8.0 \pm 0.10]$	0.150 [3.80]	0.313 [7.95]
	E	16	[0.0 ± 0.10]	0.173 [4.40]	0.343 [8.70]
	F	16	-	0.205 [5.20]	0.309 [7.85]
50 <b>7</b> D	H	16	0.476 ± 0.004	0.224 [5.70]	0.313 [7.95]
597D T97	M	16	$[12.0 \pm 0.1]$	0.193 [4.90]	0.339 [8.60]
13008	N	16	[	0.283 [7.20]	0.323 [8.20]
	R	16		0.159 [4.05]	0.313 [7.95]
	V	12	0.317 ± 0.004 [8.0 ± 0.10]	0.088 [2.23]	0.300 [7.62]
	Z	16	0.476 ± 0.004 [12.0 ± 0.1]	0.239 [6.06]	0.311 [7.90]
	A	8	0.457 0.004	0.063 [1.60]	0.152 [3.86]
	В	12	0.157 ± 0.004 [4.0 ± 0.10]	0.088 [2.23]	0.166 [4.21]
	С	12	[4.0 ± 0.10]	0.117 [2.97]	0.290 [7.36]
	D	12	0.317 ± 0.004	0.119 [3.02]	0.296 [7.52]
T0.5	R	12	$[8.0 \pm 0.10]$	0.149 [3.78]	0.296 [7.52]
T95	S	8		0.058 [1.47]	0.149 [3.78]
	V	8	1	0.060 [1.52]	0.150 [3.80]
	X	12	$0.157 \pm 0.004$	0.069 [1.75]	0.296 [7.52]
	Y	12	$[4.0 \pm 0.10]$	0.089 [2.26]	0.296 [7.52]
-	Z	12	1	0.114 [2.89]	0.288 [7.31]
	В	12	0.157 ± 0.004	0.088 [2.23]	0.166 [4.21]
	C	12	$[4.0 \pm 0.10]$	0.117 [2.97]	0.290 [7.36]
14002	D	12	0.317 ± 0.004	0.119 [3.02]	0.296 [7.52]
	R	12	$[8.0 \pm 0.10]$	0.119 [3.02]	0.296 [7.52]
			$0.476 \pm 0.004$		
T96	R	16	[12.0 ± 0.1]	0.159 [4.05]	0.313 [7.95]
T00	F	16	0.476 ± 0.004	0.239 [6.06]	0.311 [7.90]
T98	M Z	16 16	$[12.0 \pm 0.1]$	0.193 [4.90] 0.272 [6.90]	0.339 [8.60] 0.307 [7.80]

## Note

 $^{(1)}\,$  H case only, packaging code T: lengthwise orientation at capacitors in tape

# PAD DIMENSIONS in inches [millimeters]

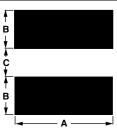


	l	A	
CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)
592D / W - 591D			
Α	0.075 [1.9]	0.050 [1.3]	0.050 [1.3]
В	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]
С	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]
••	0.050 [0.5]	Anode pad: 0.095 [2.4]	0.400 [0.5]
М	0.256 [6.5]	Cathode pad: 0.067 [1.7]	0.138 [3.5]
	0.040 [0.4]	Anode pad: 0.095 [2.4]	0.440.[0.0]
R	0.240 [6.1]	Cathode pad: 0.067 [1.7]	0.118 [3.0]
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]
X	0.310 [7.9]	0.120 [3.0]	0.360 [9.2]
595D - 594D	L		
T	0.059 [1.5]	0.028 [0.7]	0.024 [0.6]
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]
А	0.083 [2.1]	0.050 [1.3]	0.050 [1.3]
В	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]
С	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]
G	0.156 [4.05]	0.090 [2.3]	0.082 [2.1]
М	0.110 [2.8]	0.087 [2.2]	0.134 [3.4]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
195D	L		
А	0.067 [1.7]	0.043 [1.1]	0.028 [0.7]
В	0.063 [1.6]	0.047 [1.2]	0.047 [1.2]
С	0.059 [1.5]	0.031 [0.8]	0.024 [0.6]
D	0.090 [2.3]	0.055 [1.4]	0.047 [1.2]
Е	0.090 [2.3]	0.055 [1.4]	0.079 [2.0]
F	0.140 [3.6]	0.063 [1.6]	0.087 [2.2]
G	0.110 [2.8]	0.059 [1.5]	0.126 [3.2]
Н	0.154 [3.9]	0.063 [1.6]	0.140 [3.6]
N	0.244 [6.2]	0.079 [2.0]	0.118 [3.0]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
S	0.079 [2.0]	0.039 [1.0]	0.039 [1.0]
V	0.114 [2.9]	0.039 [1.0]	0.039 [1.0]
X	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]
Υ	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]
Z	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]



Vishay Sprague

## **PAD DIMENSIONS** in inches [millimeters]



		— A ——	
CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)
CWR06 / CWR16 / CWR26 - 194	D - 695D		
Α	0.065 [1.6]	0.50 [1.3]	0.040 [1.0]
В	0.065 [1.6]	0.70 [1.8]	0.055 [1.4]
С	0.065 [1.6]	0.70 [1.8]	0.120 [3.0]
D	0.115 [2.9]	0.70 [1.8]	0.070 [1.8]
E	0.115 [2.9]	0.70 [1.8]	0.120 [3.0]
F	0.150 [3.8]	0.70 [1.8]	0.140 [3.6]
G	0.125 [3.2]	0.70 [1.8]	0.170 [4.3]
Н	0.165 [4.2]	0.90 [2.3]	0.170 [4.3]
T95			
В	0.120 [3.0]	0.059 [1.5]	0.059 [1.5]
С	0.136 [3.5]	0.090 [2.3]	0.120 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.136 [3.47]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
S	0.080 [2.03]	0.040 [1.02]	0.040 [1.02]
V	0.114 [2.9]	0.040 [1.02]	0.040 [1.02]
X, Y, Z	0.114 [2.9]	0.065 [1.65]	0.122 [3.1]
14002			
В	0.120 [3.0]	0.059 [1.5]	0.059 [1.5]
С	0.136 [3.5]	0.090 [2.3]	0.120 [3.1]
D	0.180 [4.6]	0.090 [2.3]	0.136 [3.47]
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
T96			
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]
597D - T97 - T98 - 13008			
D, E, V	0.196 [4.9]	0.090 [2.3]	0.140 [3.6]
F, R, Z	0.260 [6.6]	0.090 [2.3]	0.140 [3.6]
M, H, N	0.284 [7.2]	0.090 [2.3]	0.140 [3.6]
		•	

3 °C/s max.

217 °C

60 s to 150 s

30 s

6 °C/s max.

8 min max.

Ramp-up rate (T<sub>L</sub> to T<sub>p</sub>)

Liquidus temperature (T<sub>L</sub>)

Time (t<sub>L</sub>) maintained above T<sub>L</sub>

classification temperature (T<sub>c</sub>)

Time 25 °C to peak temperature

Ramp-down rate  $(T_p \text{ to } T_L)$ 

Ramp-down

Peak package body temperature (T<sub>p</sub>) Time (t<sub>o</sub>)\* within 5 °C of the specified Vishay Sprague

### **RECOMMENDED REFLOW PROFILES** Capacitors should withstand reflow profile as per J-STD-020 standard, three cycles. T<sub>C</sub> - 5 °C Max. ramp-up rate = 3 °C/s Max. ramp-down rate = $6 \, ^{\circ}\text{C/s}$ TEMPERATURE (°C) $T_{s max.}$ Preheat area T<sub>s min.</sub> 25 Time 25 °C to peak TIME (s) **PROFILE FEATURE SnPb EUTECTIC ASSEMBLY LEAD (Pb)-FREE ASSEMBLY** Preheat / soak Temperature min. (T<sub>s min.</sub>) 100 °C 150 °C Temperature max. (T<sub>s max.)</sub> 150 °C 200 °C Time ( $t_s$ ) from ( $T_{s min.}$ to $T_{s max.}$ ) 60 s to 120 s 60 s to 120 s Ramp-up

3 °C/s max.

183 °C

60 s to 150 s

20 s

6 °C/s max.

6 min max.

Depends on type and case - see table below

PEAK PACKAGE BODY TEMPERATURE (Tp)				
TVDE / OASE OODE	PEAK PACKAGE BOD	Y TEMPERATURE (T <sub>p</sub> )		
TYPE / CASE CODE	SnPb EUTECTIC PROCESS	LEAD (Pb)-FREE PROCESS		
591D / 592D - all cases, except X25H, M and R cases	235 °C	260 °C		
591D / 592D - X25H, M and R cases	220 °C	250 °C		
594D / 595D - all cases except C, D, and R	235 °C	260 °C		
594D / 595D - C, D, and R case	220 °C	250 °C		
T95 A, B, S, V, X, Y cases	235 °C	260 °C		
T95 C, D, R, and Z cases	220 °C	250 °C		
14002 B case	235 °C	n/a		
14002 C, D, and R cases	220 °C	n/a		
T96 R case	220 °C	250 °C		
195D all cases, except G, H, R, and Z	235 °C	260 °C		
195D G, H, R, and Z cases	220 °C	250 °C		
695D all cases, except G and H cases	235 °C	260 °C		
695D G, H cases	220 °C	250 °C		
597D, T97, T98 all cases, except V case	220 °C	250 °C		
597D, T97, T98 V case	235 °C	260 °C		
194D all cases, except H and G cases	235 °C	260 °C		
194D H and G cases	220 °C	250 °C		

# Vishay Sprague

### **GUIDE TO APPLICATION**

 AC Ripple Current: the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R<sub>ESR</sub> = the capacitor equivalent series resistance at the specified frequency

2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R<sub>ESR</sub> = the capacitor equivalent series resistance at the specified frequency

Z = the capacitor impedance at the specified frequency

- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
- 3. **Reverse Voltage:** solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at +85 °C.
- 4. **Temperature Derating:** if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

TEMPERATURE	DERATING FACTOR
+25 °C	1.0
+85 °C	0.9
+125 °C	0.4

5. Power Dissipation: power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I<sub>RMS</sub> value be established when calculating permissible operating levels. (Power dissipation calculated using derating factor (see paragraph 4)).

- 6. Attachment:
- 6.1 **Soldering:** capacitors can be attached by conventional soldering techniques: vapor phase, convection reflow, infrared reflow, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see <a href="https://www.vishay.com/doc?40214">www.vishay.com/doc?40214</a>.
- Recommended Mounting Pad Geometries: the nib
  must have sufficient clearance to avoid electrical
  contact with other components. The width
  dimension indicated is the same as the maximum
  width of the capacitor. This is to minimize lateral
  movement.
- 8. Cleaning (Flux Removal) After Soldering:

  TANTAMOUNT<sup>TM</sup> capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.